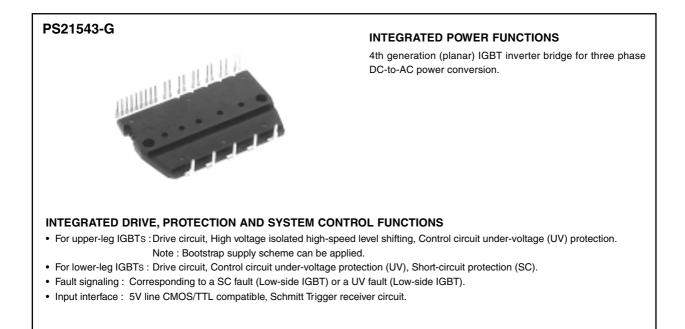
MITSUBISHI SEMICONDUCTOR <Intelligent Power Module>

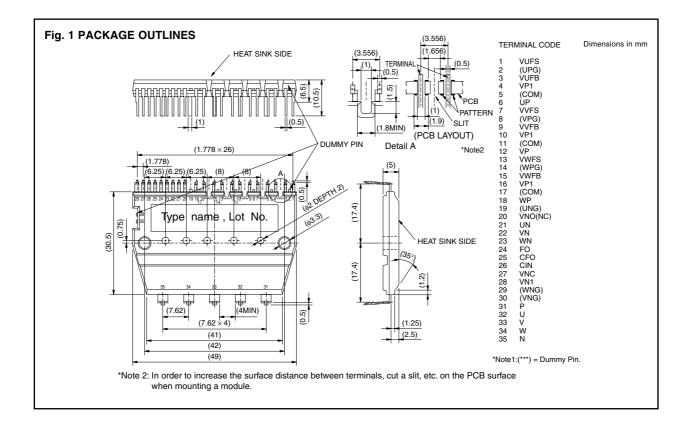
PS21543-G

TRANSFER-MOLD TYPE INSULATED TYPE



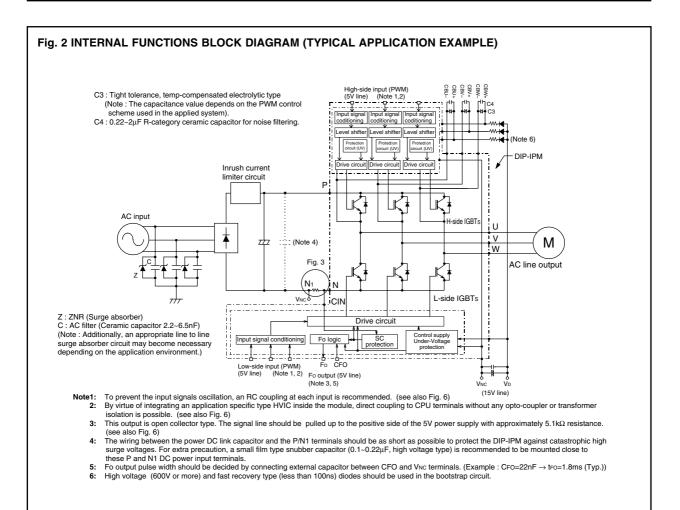
APPLICATION

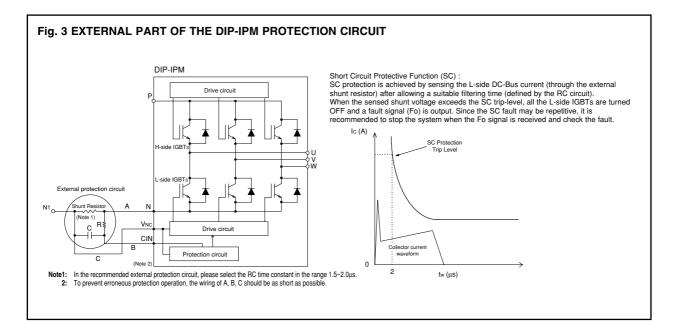
AC100V~200V three-phase inverter drive for small power motor control.





TRANSFER-MOLD TYPE INSULATED TYPE







TRANSFER-MOLD TYPE INSULATED TYPE

MAXIMUM RATINGS (T_j = 25° C, unless otherwise noted) **INVERTER PART**

| Symbol | Parameter | Condition | Ratings | Unit |
|------------|------------------------------------|--|----------|------|
| Vcc | Supply voltage | Applied between P-N | 450 | V |
| VCC(surge) | Supply voltage (surge) | Applied between P-N | 500 | V |
| VCES | Collector-emitter voltage | | 600 | V |
| ±IC | Each IGBT collector current | Tf = 25°C | 10 | A |
| ±Іср | Each IGBT collector current (peak) | Tf = 25°C, instantaneous value (pulse) | 20 | A |
| PC | Collector dissipation | Tf = 25°C, per 1 chip | 25 | W |
| Tj | Junction temperature | (Note 1) | -20~+150 | °C |

Note 1 : The maximum junction temperature rating of the power chips integrated within the DIP-IPM is 150°C (@ Tf \leq 100°C). However, to ensure safe operation of the DIP-IPM, the average junction temperature should be limited to Tj(ave) \leq 125°C (@ Tf \leq 100°C).

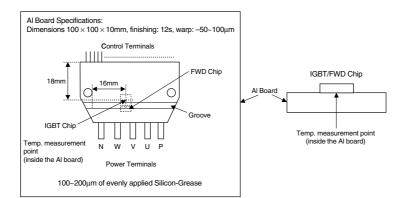
CONTROL (PROTECTION) PART

| Symbol | Parameter | Condition | Ratings | Unit |
|--------|-------------------------------|--|-------------|------|
| VD | Control supply voltage | Applied between VP1-VNC, VN1-VNC | 20 | V |
| Vdb | Control supply voltage | Applied between VUFB-VUFS, VVFB-VVFS, VWFB-VWFS | 20 | V |
| VCIN | Input voltage | Applied between UP, VP, WP-VNC, UN, VN, WN-VNC | -0.5~+5.5 | V |
| VFO | Fault output supply voltage | Applied between FO-VNC | -0.5~VD+0.5 | V |
| IFO | Fault output current | Sink current at Fo terminal | 15 | mA |
| Vsc | Current sensing input voltage | Applied between CIN-VNC | -0.5~VD+0.5 | V |

TOTAL SYSTEM

| Symbol | Parameter | Condition | Ratings | Unit |
|-----------|--|--|----------|------|
| VCC(PROT) | Self protection supply voltage limit (short-circuit protection capability) | $V_D = 13.5 \sim 16.5 V$, Inverter part T _j = 125°C, non-repetitive, less than 2 µs | 400 | v |
| Tf | Heat-fin operation temperature | (Note 2) | -20~+100 | °C |
| Tstg | Storage temperature | | -40~+125 | °C |
| Viso | Isolation voltage | 60Hz, Sinusoidal, AC 1 minute, connection pins to heat-sink plate | 2500 | Vrms |

Note 2 : Tr MEASUREMENT POINT





TRANSFER-MOLD TYPE INSULATED TYPE

THERMAL RESISTANCE

| Cumphial | Devenenter | Condition | Limits | | | - Unit |
|------------------|-------------------------------|-------------------------------------|--------|------|-----|--------|
| Symbol Parameter | Condition | | Тур. | Max. | | |
| Rth(j-f)Q | Junction-to-heat sink thermal | Inverter IGBT part (per 1/6 module) | _ | — | 5.0 | 0000 |
| Rth(j-f)F | resistance | Inverter FWD part (per 1/6 module) | | — | 6.5 | °C/W |

Note 3: Grease with good thermal conductivity should be applied evenly about +100µm ~ +200µm on the contact surface of a DIP-IPM and a Heat sink.

ELECTRICAL CHARACTERISTICS (Tj = 25° C, unless otherwise noted) **INVERTER PART**

| Or mark at | Damanatan | Limits | | | Condition | | Unit |
|------------|--|----------------------------------|----------------------|------|-----------|------|------|
| Symbol | Parameter | | Condition | | Тур. | Max. | Unit |
| VCE(sat) | Collector-emitter saturation | VD = VDB = 15V | IC = 10A, Tj = 25°C | — | 1.55 | 2.15 | |
| | voltage | VCIN = 0V | IC = 10A, Tj = 125°C | — | 1.65 | 2.25 | V |
| VEC | FWD forward voltage | Tj = 25°C, –IC = 10A, VCIN = 5V | | — | 2.10 | 2.85 | V |
| ton | Vcc = 300V, VD = VDB Ic = 10A, Tj = 125°C Switching times Inductive load (upper-let) | | =15V | 0.10 | 0.60 | 1.10 | μs |
| trr | | | | — | 0.10 | — | μs |
| tc(on) | | | wer arm) | — | 0.30 | 0.70 | μs |
| toff | | $V_{CIN} = 5 \leftrightarrow 0V$ | , | — | 1.50 | 2.70 | μs |
| tc(off) | | | | | 0.80 | 1.70 | μs |
| ICES | Collector-emitter cut-off | VCE = VCES | $T_j = 25^{\circ}C$ | | _ | 1 | mA |
| | current | VCE = VCES | Tj = 125°C | — | — | 10 | IIIA |

CONTROL (PROTECTION) PART

| O make at | Demonster | Parameter Condition | | Limits | | | 11-24 |
|-----------|---------------------------------|--|---------------------------------|--------|------|------|-------|
| Symbol | Parameter | | | Min. | Тур. | Max. | Unit |
| VD | Control supply voltage | Applied between \ | /p1-VNC, VN1-VNC | 13.5 | 15.0 | 16.5 | V |
| Vdb | Control supply voltage | Applied between \ | /UFB-VUFS, VVFB-VVFS, VWFB-VWFS | 13.5 | 15.0 | 16.5 | V |
| ID | Circuit current | VD = VDB =15V | Total of VP1-VNC, VN1-VNC | _ | — | 8.50 | mA |
| U | Circuit current | VCIN = 5V | VUFB-VUFS, VVFB-VVFS, VWFB-VWFS | _ | — | 1.00 | ШA |
| VFOH | | Vsc = 0V, Fo = 10 | kΩ 5V pull-up | 4.9 | _ | _ | V |
| VFOL | Fault output voltage | Vsc = 1V, Fo = 10 | kΩ 5V pull-up | _ | 0.8 | 1.2 | V |
| VFOsat | - | VSC = 1V, IFO = 15mA | | 0.8 | 1.2 | 1.8 | V |
| tdead | Arm shoot-through blocking time | Relates to corresponding input signal for blocking arm shoot-through. $-20^{\circ}C \le Tf \le 100^{\circ}C$ | | 3 | | _ | μs |
| VSC(ref) | Short-circuit trip level | Tj = 25°C, VD = 15 | 5V (Note 4) | 0.45 | 0.5 | 0.55 | V |
| UVDBt | | | Trip level | 10.0 | _ | 12.0 | V |
| UVDBr | Supply circuit under-voltage | Ti ≤ 125°C | Reset level | 10.5 | — | 12.5 | V |
| UVDt | protection | 1j ≤ 125 C | Trip level | 10.3 | — | 12.5 | V |
| UVDr | | | Reset level | 10.8 | — | 13.0 | V |
| tFO | Fault output pulse width | CFO = 22nF (Note 5) | | 1.0 | 1.8 | _ | ms |
| Vth(on) | ON threshold voltage | Applied between: | | 0.8 | 1.4 | 2.0 | V |
| Vth(off) | OFF threshold voltage | UP, VP, WP-VNC, U | JN, VN, WN-VNC | 2.5 | 3.0 | 4.0 | V |

Note 4: Short-circuit protection operates only at the low-arms. Please select the value of the external shunt resistor such that the SC trip level is less than 17A

5: Fault signal is outputted when the low-arm short-circuit or control supply under-voltage protective functions operate. The fault output pulse-width tFO depends on the capacitance value of CFO according to the following approximate equation. : $CFO = (12.2 \times 10^{-6}) \times tFO [F]$

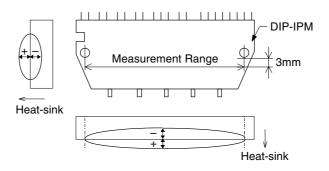


TRANSFER-MOLD TYPE INSULATED TYPE

MECHANICAL CHARACTERISTICS AND RATINGS

| Devemeter | Candition | | | Unit | | |
|---------------------------|-------------------------|--------------|------|------|------|-------|
| Parameter | Condition | | Min. | Тур. | Max. | Unit |
| Mounting torque | Mounting screw : M3 | — | 0.59 | 0.78 | 0.98 | N∙m |
| Terminal pulling strength | Weight 9.8N | EIAJ-ED-4701 | 10 | — | | S |
| Bending strength | Weight 4.9N. 90deg bend | EIAJ-ED-4701 | 2 | — | | times |
| Weight | | — | — | 20 | | g |
| Heat-sink flatness | (Note 6) | _ | -50 | — | 100 | μm |

Note 6: Measurement point of heat-sink flatness



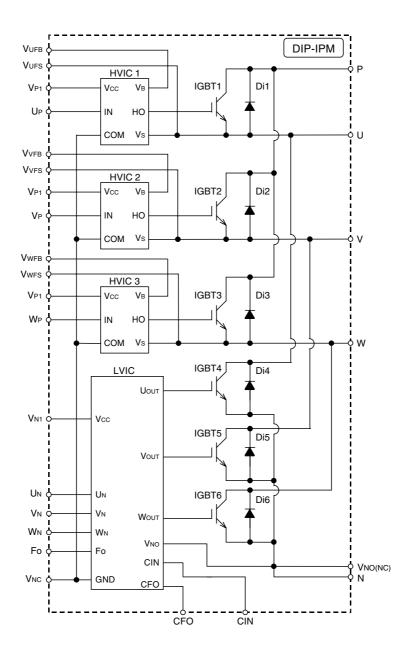
RECOMMENDED OPERATION CONDITIONS

| Currente e l | Deverenter | Condition | | Limits | | |
|-------------------------|---------------------------------|--|------|---------|------|------|
| Symbol | Parameter Condition | | Min. | Тур. | Max. | Unit |
| Vcc | Supply voltage | Applied between P-N | 0 | 300 | 400 | V |
| Vd | Control supply voltage | Applied between VP1-VNC, VN1-VNC | 13.5 | 15.0 | 16.5 | V |
| Vdb | Control supply voltage | Applied between VUFB-VUFS, VVFB-VVFS, VWFB-VWFS | 13.5 | 15.0 | 16.5 | V |
| $\Delta VD, \Delta VDB$ | Control supply variation | | -1 | — | 1 | V/µs |
| tdead | Arm shoot-through blocking time | Relates to corresponding input signal for blocking arm shoot-through | 3 | — | — | μs |
| fpwm | PWM input frequency | Tj ≤ 125°C, Tf ≤ 100°C | | 5 | _ | kHz |
| VCIN(ON) | Input ON voltage | Applied between UP, VP, WP-VNC, UN, VN, WN-VNC | | 0~0.65 | | V |
| VCIN(OFF) | Input OFF voltage | | | 4.0~5.5 | | V |



PS21543-G TRANSFER-MOLD TYPE INSULATED TYPE

Fig. 4 THE DIP-IPM INTERNAL CIRCUIT



Note: The IGBTs gates and the HVICs COM terminals are connected to the dummy pins.



TRANSFER-MOLD TYPE INSULATED TYPE

Fig. 5 TIMING CHARTS OF THE DIP-IPM PROTECTIVE FUNCTIONS

[A] Short-Circuit Protection (N-side only)

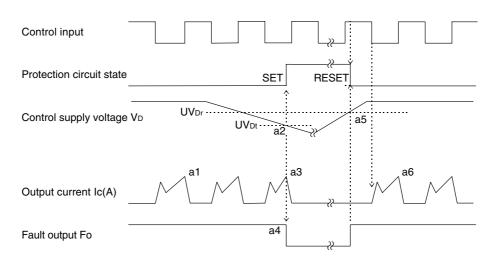
- (For the external shunt resistor and CR connection, please refer to Fig. 3.)
- a1. Normal operation : IGBT ON and carrying current.
- a2. Short-circuit current detection (SC trigger).
- a3. IGBT gate interrupt.
- a4. IGBT turns OFF.
- a5. Fo timer operation starts : The pulse width of the Fo signal is set by the external capacitor CFo.
- a6. Input "H" : IGBT OFF state.
- a7. Input "L" : IGBT ON state.
- a8. IGBT OFF state.

| N-side control input | a6 a7 , |
|-------------------------------------|--------------------------------|
| Protection circuit state | |
| Internal IGBT gate | a3 |
| | SC 4 |
| Output current Ic(A) | |
| Sense voltage of the shunt resistor | SC reference voltage |
| | CR circuit time constant DELAY |
| Fault output Fo | a5 |

[B] Under-Voltage Protection (N-side, UVD)

- a1. Normal operation : IGBT ON and carrying current.a2. Under-voltage trip (UVDt).a3. IGBT OFF in spite of control input condition.

- a4. Fo timer operation starts.
- a5. Under-voltage reset (UVDr)
- a6. Normal operation : IGBT ON and carrying current.



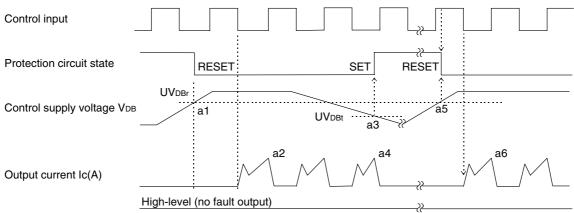


TRANSFER-MOLD TYPE INSULATED TYPE

[C] Under-Voltage Protection (P-side, VDB)

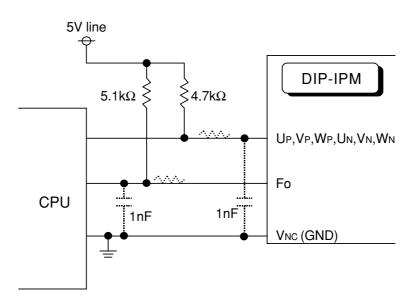
- a1. Control supply voltage rises : After the voltage level reachs UVDBr, the circuits start to operate when the next input is applied. a2. Normal operation : IGBT ON and carrying current. a3. Under-voltage trip (UVDBt).

- a4. IGBT OFF in spite of control input condition (there is no Fo signal output).
- a5. Under-voltage reset (UVDBr).
- a6. Normal operation : IGBT ON and carrying current.



Fault output Fo

Fig. 6 RECOMMENDED CPU I/O INTERFACE CIRCUIT

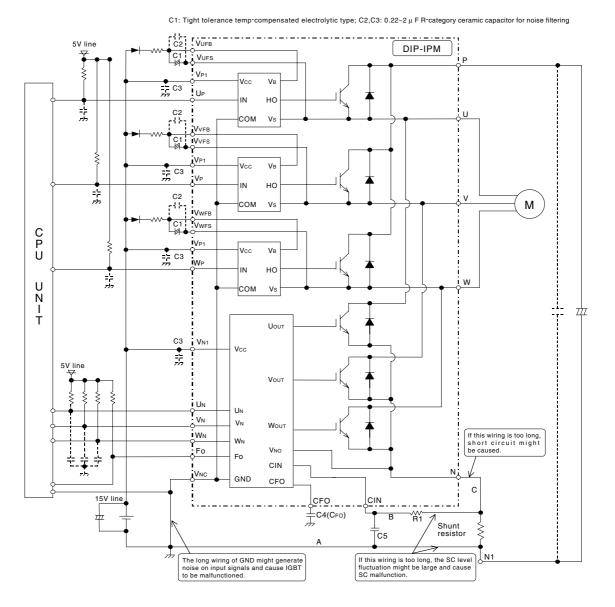


Note : RC coupling at each input (parts shown dotted) may change depending on the PWM control scheme used in the application and on the wiring impedance of the application's printed circuit board.



TRANSFER-MOLD TYPE INSULATED TYPE

Fig. 7 TYPICAL DIP-IPM APPLICATION CIRCUIT EXAMPLE



Note 1 : To prevent the input signals oscillation, an RC coupling at each input is recommended, and the wiring of each input should be as short as possible (less than 2cm).

2: By virtue of integrating an application specific type HVIC inside the module, direct coupling to CPU terminals without any opto-coupler or transformer isolation is possible.

3: Fo output is open collector type. This signal line should be pulled up to the positive side of the 5V power supply with approximately 5.1kΩ resistance.

4: Fo output pulse width should be decided by connecting an external capacitor between CFO and VNC terminals (CFO). (Example : CFO = 22 nF \rightarrow tFO = 1.8 ms (typ.))

- 5: Each input signal line should be pulled up to the positive side of the 5V power supply with approximately 4.7kΩ resistance (other RC coupling circuits at each input may be needed depending on the PWM control scheme used and on the wiring impedances of the system's printed circuit board). Approximately a 0.22~2µF by-pass capacitor should be used across each power supply connection terminals

6 : To prevent errors of the protection function, the wiring of A, B, C should be as short as possible.
7 : In the recommended protection circuit, please select the R1Cs time constant in the range of 1.5~2µs.

8: Each capacitor should be put as nearby the terminals of the DIP-IPM as possible.

9: To prevent surge destruction, the wiring between the smoothing capacitor and the P&N1 terminals should be as short as possible. Approximately a 0.1~0.22µF snubber capacitor between the P&N1 terminals is recommended.

